# PC817 Series

\*\* Lead forming type (I type) and taping reel type (P type) are also available. (PC817I/PC817P) (Page 656)
\*\*XTUV (VDE0884) approved type is also available as an option.

#### ■ Features

1. Current transfer ratio

(CTR: MIN. 50% at  $I_F=5mA$ )

2. High isolation voltage between input and output ( $V_{\rm iso}$ : 5 000 $V_{\rm rms}$ )

3. Compact dual-in-line package

PC817: 1-channel type

**PC827**: 2-channel type **PC837**: 3-channel type

PC847: 4-channel type

4. Recognized by UL, file No. E64380

## ■ Applications

**Photocoupler** 

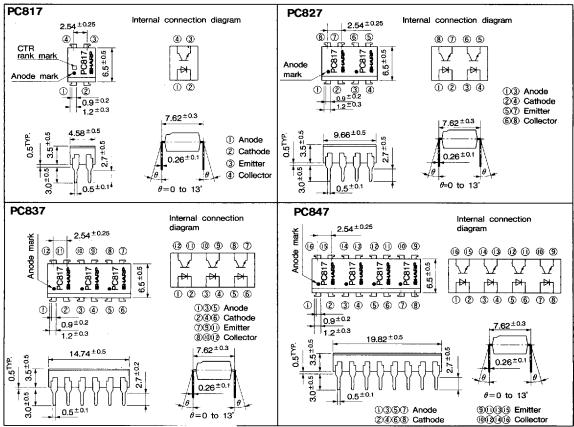
- 1. Computer terminals
- 2. System appliances, measuring instruments

**High Density Mounting Type** 

- Registers, copiers, automatic vending machines
- 4. Electric home appliances, such as fan heaters, etc.
- 5. Medical instruments, physical and chemical equipment
- 6. Signal transmission between circuits of different potentials and impedances

#### Outline Dimensions

(Unit: mm)



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"In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device."

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#### **■ Absolute Maximum Ratings**

 $(Ta=25^{\circ}C)$ 

	Parameter	Symbol Rating		Unit	
Input	Forward current	$I_{\mathrm{F}}$	50	mA	
	*1Peak forward current	I <sub>FM</sub> 1		A	
	Reverse voltage	VR	6	V	
	Power dissipation	P	70	mW	
Output	Collector-emitter voltage	V <sub>CEO</sub> 35		V	
	Emitter-collector voltage	V <sub>ECO</sub>	6	V	
	Collector current	Ic	50	mA	
	Collector power dissipation	Pc	150	mW	
	Total power dissipation	P <sub>tot</sub>	200	mW	
	*2Isolation voltage	Viso	5 000	$V_{rms}$	
	Operating temperature	$T_{opr}$	-30  to  +100	$^{\circ}$ C	
	Storage temperature	$T_{\text{stg}}$	-55 to +125	°C	
	*3Soldering temperature	T <sub>sol</sub>	260	°C	

<sup>\*1</sup> Pulse width  $\leq 100 \,\mu$ s, Duty ratio = 0.001

### **■ Electro-optical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage		$V_{\mathrm{F}}$	$I_F = 20 \text{mA}$		1.2	1.4	V
	Peak forward voltage		V <sub>FM</sub>	I <sub>FM</sub> =0.5A	-		3.0	V
	Reverse current		$I_R$	$V_R = 4V$	<u> </u>	-	10	μΑ
	Terminal capacitance		Ct	V=0, $f=1kHz$	_	30	250	pF
Output	Collector dark	current	ICEO	$V_{CE} = 20V$	-	_	$10^{-7}$	Α
Transfer charac- teristics	*4Current transfer ratio		CTR	$I_F=5mA$ , $V_{CE}=5V$	50	-	600	%
	Collector-emitter saturation voltage		V <sub>CE(sat)</sub>	$I_F = 20 \text{mA}, I_C = 1 \text{mA}$	_	0.1	0.2	V
	Isolation resistance		Riso	DC500V, 40 to 60%RH	$5 \times 10^{10}$	1011	_	Ω
	Floating capacitance		Cf	V=0, $f=1MHz$	-	0.6	1.0	pF
	Cut-off frequency		fc	$V_{CE} = 5V$ , $I_{C} = 2mA$ , $R_{L} = 100\Omega$ , $-3dB$		80	_	kHz
	Response time	Rise time	t <sub>r</sub>	$V_{CE}=2V$ , $I_C=2mA$ , $R_L=100\Omega$	_	4	18	μs
		Fall time	tí		_	3	18	μS

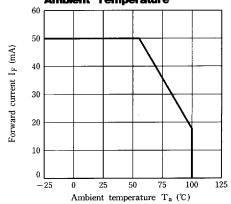
**<sup>\*</sup>**4 Classification table of current transfer ratio is shown below.

Model No.	Rank mark	CTR (%)
PC817A	A	80 to 160
PC817B	В	130 to 260
PC817C	С	200 to 400
PC817D	D	300 to 600
PC8 × 7AB	A or B	80 to 260
PC8 × 7BC	B or C	130 to 400
PC8 × 7CD	C or D	200 to 600
PC8※7AC	A, B or C	80 to 400
PC8 × 7BD	B, C or D	130 to 600
PC8 × 7AD	A, B, C or D	80 to 600
PC8 ** 7	A, B, C, D or No mark	50 to 600

**<sup>※</sup>**∶1 or 2 or 3 or 4

Fig. 1 Forward Current vs.

Ambient Temperature



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<sup>\*2 40</sup> to 60%RH, AC for 1 minute

<sup>\*3</sup> For 10 seconds

Fig. 2 Collector Power Dissipation VS.
Ambient Temperature

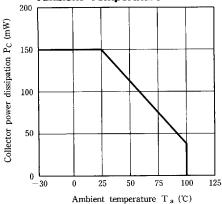


Fig. 4 Current Transfer Ratio vs. Forward Current

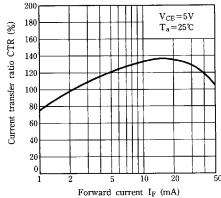


Fig. 6 Collector Current vs. Collector-emitter Voltage

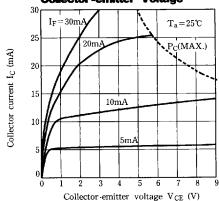


Fig. 3 Peak Forward Current vs. Duty Ratio

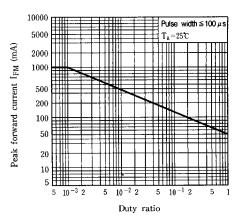


Fig. 5 Forward Current vs. Forward Voltage

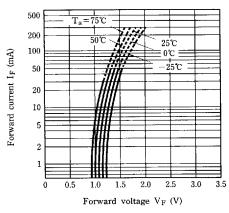


Fig. 7 Relative Current Transfer Ratio vs.
Ambient Temperature

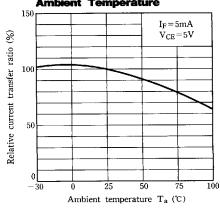


Fig. 8 Collector-emitter Saturation Voltage vs.
Ambient Temperature

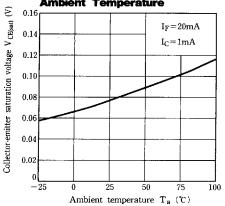
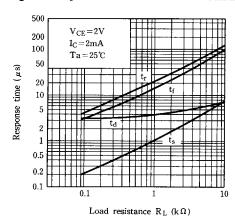
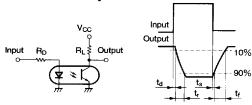


Fig.10 Response Time vs. Load Resistance



**Test Circuit for Response Time** 



Test Circuit for Frepuency Response

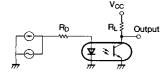


Fig. 9 Collector Dark Current vs.
Ambient Temperature

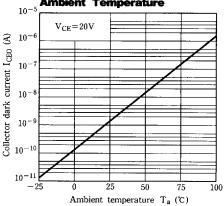


Fig.11 Frequency Response

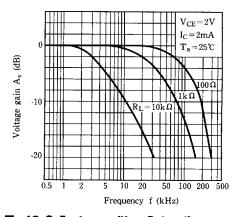
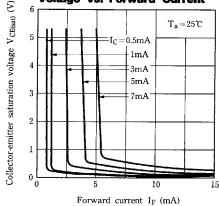


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



• Please refer to the chapter "Precautions for Use" (Page 78 to 93)

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www.datasheetcatalog.com

Datasheets for electronics components.